EMC210 - 8GB ~ 32GB

e.MMC 4.51 / BGA-153

Transcend's e.MMC-EMC210, is an Embedded Flash Drive (EFD) designed for industrial applications such as embedded system, vehicle entertainment system, GPS, games, email, office, etc. It is a hybrid device combining an embedded thin flash controller and standard MLC NAND flash memory, supporting an industry standard e.MMC 4.51 interface.

The outstanding performance and strict environment test enable Transcend's e.MMC 210 to fulfill the needs of a wide variety of industrial application devices. EMC 210 also provide 8~32GB of capacities in JEDEC compatible form factor and is an ideal solution for the vendors who require easy integration, fast entry to market and high storage capacity.

Features

- Compliant with JEDEC e.MMC Specification Ver. 4.51
- Supports three data bus widths: 1bit(default), 4bit, 8bit.
- Uses an embedded thin memory controller and MLC NAND flash
- Mechanical design complies with JESD84-C44 Specification
- Dual power system
- Core voltage (VCC) 2.7-3.6V
- I/O (VCCQ) voltage, either: 1.7-1.95V or 2.7-3.6V
- Variable clock frequencies of 0-200 MHz
- Supports three data bus widths: 1bit(default), 4bit, 8bit.
- Static global wear leveling
- BCH ECC:53bit/1KB
- Fully cycle environment test
- RoHS compliant



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e.MMC Bus and Power Lines

Transcend's e.MMC bus has the following communication and power lines:

- CMD: Command is a bidirectional signal. The host and Transcend's e.MMC operate in two modes, open drain and push-pull.
- DAT0-7: Data lines are bidirectional signals. Host and Transcend's e.MMC operate in push-pull mode.
- CLK: Clock input.
- RST_n: Hardware Reset Input
- VCCQ: VCCQ is the power supply line for host interface.

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- VCC: VCC is the power supply line for internal flash memory.
- VDDi: VDDi is e.MMC's internal power node, not the power supply. Connect 0.1µF capacitor from VDDi to ground.
- VSS, VSSQ : Ground lines

(Bus Signal Level)

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Parameter	Min	Max	Unit	Remark
Supply voltage (3.3V)	2.7	3.6	V	
Supply voltage (1.8V)	1.7	1.95	V	
I/O Leakage current	-10	10	uA	
Open-Drain bus signal level				
Output high voltage (Vон)	VCCQ - 0.2		V	
Output Low voltage (VoL)		0.3	V	IoL = 2mA
Push-Pull bus signal level (2.7~3.6)	V)			
Output high voltage (Vон)	0.75 * VCCQ		V	Іон = -100uA @ VDD min
Output Low voltage (VoL)		0.125 * VCCQ	V	loL = 100uA @ VDD min
Input high voltage (Vін)	0.625 * VCCQ	VCCQ + 0.3	V	
Input Low voltage (VIL)	GND – 0.3	0.25 * VCCQ	V	
Push-pull bus signal level (1.70V~1	.95V)			
Output high voltage (Vон)	VCCQ - 0.45		V	Iон = -2 mA
Output Low voltage (VoL)		0.45	V	IoL = 2 mA
Input high voltage (VIH)	0.65 * VCCQ	VCCQ + 0.3	V	
Input Low voltage (V⊫)	GND – 0.3	0.35 * VDD	V	



e.MMC 4.51 selected feature overview

Power Off Notification

The host should notify the device before it powers the device off. This allows the device to better prepare itself for being powered off. For more details, refer to section 6.6.36 of the JEDEC Standard Specification NO. JESD84-B451.

• Packed Commands

Read and write commands can be packed in groups of commands (either all read or all write) that transfer the data for all commands in the group in one transfer on the bus, to reduce overheads. For more details, refer to section 6.6.29 of the JEDEC Standard Specification NO. JESD84-B451.

Boot Partition

EMC210 supports e.MMC 4.51 boot operation modes. Boot partition size is reflected in BOOT_SIZE_MULT register value in extended CSD.

• Automatic Sleep Mode

If there is no further command issued by the host in 11mS duration, after the previously issued command is completed, the device enters "Power Saving Mode" to reduce power consumption. The host does not have to take any action for this to occur. However, if host want to achieve the lowest sleep current, the host needs to shut down its clock to the memory device. When the host is ready to access a memory device in sleep mode, any command issued to it will cause devices to exit sleep mode.

• Sleep (CMD5)

EMC210 may be switched between a sleep state and a standby state by SLEEP/AWAKE (CMD5). In the sleep state the power consumption of EMC210 is minimized. For more details, refer to section 6.6.21 of the JEDEC Standard Specification No. JESD84-451.

• Enhanced Reliable Write

EMC210 supports enhanced reliable write as defined in e.MMC 4.51 spec. Enhanced reliable write is a special write mode in which the old data pointed to by a logical address must remain unchanged until the new data written to same logical address has been successfully programmed. This is to ensure that the target address updated by the reliable write transaction never contains undefined data. When writing in reliable write mode, data will remain valid even if a sudden power loss occurs during programming.

Sanitize

The sanitize operation is a feature, in addition to Trim and Erase is used to remove data from EMC210. The use of sanitize operation requires EMC210 to physically remove data from the



unmapped user address space. For more details, refer to section 6.6.13 of the JEDEC Standard Specification NO.JESD84-B451.

• Discard

The discard is similar operation to Trim. The discard function allows the host to identify data that's no longer required so that EMC210 can erase the data if necessary during background erase events. For more details, refer to section 6.6.14 of the JEDEC Standard Specification NO.JESD84-B451.

• Erase

In addition to the implicit erase executed by EMC210 as part of the write operation, provides a host explicit erase function. For more details, refer to section 6.6.11 of the JEDEC Standard Specification NO.JESD84-B451.

• Trim

The Trim operation is similar to the default erase operation described above. The Trim function applies the erase operation to write blocks instead of erase groups. The Trim function allows the host to identify data that's no longer required so that EMC210 can erase the data if necessary during background erase events. For more details, refer to section 6.6.12 of the JEDEC Standard Specification NO.JESD84-B451.

• Partition management

EMC210 offers the possibility for the host to configure addition split local memory partitions with independent addressable space starting from logical address 0x00000000 for different usage models. Therefore memory block area scan be classified as follows:

- Two Boot Area partitions, whose size is 4MB and from which booting from EMC210 can be performed.
- One RPMB partition accessed through a trusted mechanism, whose size is defined as multiple of 128KB.
- ✓ Four General Purpose Area Partition to store sensitive data or for other host usage models. The size of these partitions is a multiple of the write protect group. Size can be programmed once in device life cycle (one-time programmable).

Quick Health Info

Transcend designs several byte in extended CSD of EMC210. Customers can read UDA and EUDA program/erase cycles information by CMD_8 and reading extended CSD structure without any performance suffer. It's well-designed for industrial use.

Write Protect Management

In order to allow the host to protect data against erase or write, EMC210 supports two levels of write protect commands. For more details, refer to section 6.6.17 of the JEDEC Standard Specification NO.JESD84-B451.



• High Priority Interrupt (HPI)

In some scenarios, different types of data on the device may have different priorities for the host. For example, writing operation may be time consuming and therefore there might be a need to suppress the writing to allow demand paging requests in order launch a process when requested by the user. For more details, refer to section 6.6.26 of the JEDEC Standard Specification NO. JESD84-B451.

• H/W Reset

Hardware reset may be used by the host to reset the device, moving the device to a Pre-idle state and disabling the power-on period write protect on blocks that was set as power-on write protect before the reset was asserted. For more details, refer to section 6.15.9 of the JEDEC Standard Specification NO.JESD84-B451.

• DDR I/F

Support DDR signaling to double bus performance. For more details, refer to JESD84-B451 standard.

Replay Protected Memory Block

A signed access to a Replay Protected Memory Block is provided. This function provides means for the system to store data to the specific memory area in an authenticated and replay protected manner. For more details, refer to section 6.6.22 of the JEDEC standard Specification NO.JESD84-B451.

Background Operation

EMC210 has various maintenance operations need to perform internally. In order to reduce latencies during time critical operation like read and write, it is better to execute maintenance operation in other times – when the host is not being serviced. For more details, refer to section 6.6.25 of the JEDEC Standard Specification NO.JESD84-B451.



Product Specifications

• Specification

P/N	Package	Ball Number	Technology
TS8GEMC210	11.5 x 13 x 1.0 mm	153	MLC
TS16GEMC210	11.5 x 13 x 1.0 mm	153	MLC
TS32GEMC210	11.5 x 13 x 1.2 mm	153	MLC

• P<u>erformanc</u>e

D/N	Performance*					
F7IN	Seq. Read	Seq. Write	Ran. Read	Ran. Write		
TS8GEMC210	140	40	2100 IOPS	600 IOPS		
TS16GEMC210	140	60	2100 IOPS	700 IOPS		
TS32GEMC210	140	60	2100 IOPS	700 IOPS		

*Depending on operating condition, the result might be different.

• Terabytes Written

P/N	Terabytes Written
TS8GEMC210	9.23 TBW.
TS16GEMC210	18.46 TBW
TS32GEMC210	36.92 TBW

*Depending on different programming behavior and type.



• Power Consumption

	Power Consumption (mA , 25℃)					
P/N	VCCQ					
	APS	Sleep	Write	Read		
TS8GEMC210	0.05	0.05	21	37		
TS16GEMC210	0.05	0.05	23	37		
TS32GEMC210	0.05	0.05	23	37		

*APS: Auto Power Suspend

• Power Supply

P/N	VCC	VCCQ
TS8GEMC210	2.7-3.6V	1.7-1.95V / 2.7-3.6V
TS16GEMC210	2.7-3.6V	1.7-1.95V / 2.7-3.6V
TS32GEMC210	2.7-3.6V	1.7-1.95V / 2.7-3.6V

*VCCQ (I/O) 3.3V is not supported in HS200 operation.

• Temperature

T	Operation	Storage
remperature	-25℃ to 85℃	-40° ℃ to 85°℃

• Moisture Sensitivity

The moisture sensitivity for EMC210 is MSL = 3.

Mechanical Property

Mechanical Property	
Shock	500G, 1ms (JESD22B104)
Vibration	20.0G, 20 - 2000Hz (JESD22B103)



Physical Specifications







CYLIDOL	DIMENSION IN MM			DIMENSION IN INCH		
STMBOL	MIN.	NOM	MAX.	MIN.	NOM	MAX.
Α			1.20			0.047
A1	0.15			0.006		
A2			0.92			0.036
b	0.25	0.30	0.35	0.010	0.012	0.014
D	12.90	13.00	13.10	0.508	0.512	0.516
E	11.40	11.50	11.60	0.449	0.453	0.457
e	0.5 BSC.			(0.020 B	SC.
JEDEC	MO-276					

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Interface Description

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153-Ball AA Device	Symbol	Туре	Ball Function	
M6	CLK	Input	Clock:	
			Each cycle directs a 1-bit transfer on the	
			command and DAT lines.	
M5	CMD	Input	Command:	
			A bidirectional channel used for device	
			initialization and command transfers.	
			Command has two operation modes:	
			 Open-drain for initialization 	
			Push-pull for fast command transfer	
A3	DAT0	I/O	Data I/O0:	
			Bidirectional channel used for data transfer.	
A4	DAT1	I/O	Data I/O1:	
			Bidirectional channel used for data transfer.	
A5	DAT2	I/O	Data I/O2:	
			Bidirectional channel used for data transfer.	
B2	DAT3	I/O	Data I/O3:	
			Bidirectional channel used for data transfer.	
B3	DAT4	I/O	Data I/O4:	
			Bidirectional channel used for data transfer.	
B4	DAT5	I/O	Data I/O5:	
			Bidirectional channel used for data transfer.	
B5	DAT6	I/O	Data I/O6:	
			Bidirectional channel used for data transfer.	
B6	DAT7	I/O	Data I/O7:	
			Bidirectional channel used for data transfer.	
K5	RST_n	Input	Reset signal pin	
E6, F5, J10, K9	VCC	Supply	VCC:	
			Flash memory I/F and Flash memory power	
			supply.	
C6, M4, N4, P3, P5	VCCQ	Supply	VCCQ:	
			Memory controller core and MMC interface	
			I/O power supply.	



153-Ball AA Device	Symbol	Туре	Ball Function
E7, G5, H10, K8	VSS	Supply	VSS:
			Flash memory I/F and Flash memory ground
			connection.
C4, N2, N5, P4, P6	VSSQ	Supply	VSSQ:
			Memory controller core and MMC I/F ground
			connection.
C2	VDDi		VDDi:
			Connect 0.1µF capacitor from VDDi to ground
Miscellaneous			
D4	NC Index	—	Index:
			Can be connected to ground or left floating.
A1, A2, A8, A9, A10, A11,	NC	—	No connect:
A12, A13, A14, B1, B7,			Can be connected to ground or left floating.
B8, B9, B10, B11, B12,			
B13, B14, C1, C3, C7, C8,			
C9, C10, C11, C12, C13,			
C14, D1, D2, D3, D12,			
D13, D14, E1, E2, E3,			
E12, E13, E14, F1, F2,			
F3, F12, F13, F14, G1,			
G2, G12, G13, G14, H1,			
H2, H3, H12, H13, H14,			
J1, J2, J3, J12, J13, J14,			
K1, K2, K3, K12, K13,			
K14, L1, L2, L3, L12, L13,			
L14, M1, M2, M3, M7, M8,			
M9, M10, M11, M12, M13,			
M14, N1, N3, N6, N7, N8,			
N9, N10, N11, N12, N13,			
N14, P1, P2, P8, P9, P11,			
P12, P13, P14			
A6, A7, C5, E5, E8, E9,	RFU	—	Reserved for future use.
E10, F10, G3, G10, H5,			Left it floating for future use.



153-Ball AA Device	Symbol	Туре	Ball Function
J5, K6, K7, K10, P7, P10			

Card Register

•OCR Register

For Transcend e.MMC, the value of 32-bit OCR register is 0xC0FF8080

Note: OCR bit [31] is set to LOW if the card has not finished the power up routine.

•	CI	D	Register
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Name	Field	Width	Value	CSD-slice
Manufacturer ID	MID	8	1Eh	[127:120]
Card/BGA	CBX	2	01h	[113:112]
OEM/Application ID	OID	8	FFh	[111:104]
Product name	PNM	48	5453454D4D43h	[103:56]
Product revision	PRV	8	Counter to indicate FW ver.	[55:48]
Product serial number	PSN	32	Random by production	[47:16]
Manufacturing date	MDT	8	Month Year	[15:8]
CRC7 checksum	CRC	7	• (Note1)	[7:1]

Note1: The description is the same as e.MMC JEDEC standard

•CSD Register

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R: Read only.

W: One time programmable and not readable.

 ${\bf R}/{\bf W}:$ One time programmable and readable.

W/E: Multiple writable with value kept after power failure, H/W reset assertion and any CMD0 reset and not readable.

R/**W**/**E**: Multiple writable with value kept after power failure, H/W reset assertion and any CMD0 reset and readable.



R/**W**/**C**_**P**: Writable after value cleared by power failure and H/W reset assertion (the value not cleared by CMD0 reset) and readable.

R/**W**/**E**_**P**: Multiple writable with value reset after power failure, H/W reset assertion and any CMD0 reset and readable.

W/**E**_**P**: Multiple writable with value reset after power failure, H/W reset assertion and any CMD0 reset and not readable.

Name	Field	Width	Cell Type	Value	CSD-slice
CSD structure	CSD_STRUCTURE	2	R	11b	[127:126]
System specification version	SPEC_VERS	4	R	0100b	[125:122]
Data read access-time 1	TAAC	8	R	27h	[119:112]
Data read access-time 2 in CLK cycles (NSAC*100)	NSAC	8	R	01h	[111:104]
Max. bus clock frequency	TRAN_SPEED	8	R	32h	[103:96]
Card command classes	CCC	12	R	0F5h	[95:84]
Max. read data block length	READ_BL_LEN	4	R	9h	[83:80]
Partial blocks for read allowed	READ_BL_PARTIAL	1	R	0b	[79:79]
Write block misalignment	WRITE_BLK_MISALIG N	1	R	0b	[78:78]
Read block misalignment	READ_BLK_MISALIGN	1	R	0b	[77:77]
DSR implemented	DSR_IMP	1	R	0b	[76:76]
Device size	C_SIZE	12	R	FFFh	[73:62]
Max. read current @ V _{DD} min	VDD_R_CURR_MIN	3	R	111b	[61:59]
Max. read current @ V_{DD}	VDD_R_CURR_MAX	3	R	111b	[58:56]



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max					
Max. write current @ V _{DD} min	VDD_W_CURR_MIN	3	R	111b	[55:53]
Max. write current @ V _{DD} max	VDD_W_CURR_MAX	3	R	111b	[52:50]
Device size multiplier	C_SIZE_MULT	3	R	111b	[49:47]
Erase group size	ERASE_GRP_SIZE	5	R	11111b	[46:42]
Erase group size multiplier	ERASE_GRP_MULT	5	R	11111b	[41:37]
Write protect group size	WP_GRP_SIZE	5	R	01111b	[36:32]
Write protect group enable	WP_GRP_ENABLE	1	R	1b	[31:31]
Manufacturer default ECC	DEFAULT_ECC	2	R	00b	[30:29]
Write speed factor	R2W_FACTOR	3	R	010b	[28:26]
Max. write data block length	WRITE_BL_LEN	4	R	9h	[25:22]
Partial blocks for write allowed	WRITE_BL_PARTIAL	1	R	0b	[21:21]
Content protection application	CONTENT_PROT_APP	1	R	0b	[16:16]
File format group	FILE_FORMAT_GRP	1	R/W	0b	[15:15]
Copy flag (OTP)	COPY	1	R/W	1b	[14:14]
Permanent write protection	PERM_WRITE_PROTE CT	1	R/W	0b	[13:13]
Temporary write protection	TMP_WRITE_PROTEC T	1	R/W/E	0b	[12:12]
File format	FILE_FORMAT	2	R/W	00b	[11:10]
ECC code	ECC	2	R/W/E	00b	[9:8]
CRC	CRC	7	R/W/E	1101001b	[7:1]
Not used, always '1'	-	1	_	1b	[0:0]



•Extended CSD register

R: Read only.

W: One time programmable and not readable.

R/**W**: One time programmable and readable.

W/E: Multiple writable with value kept after power failure, H/W reset assertion and any CMD0 reset and not readable.

R/**W**/**E**: Multiple writable with value kept after power failure, H/W reset assertion and any CMD0 reset and readable.

R/**W**/**C**_**P**: Writable after value cleared by power failure and H/W reset assertion (the value not cleared by CMD0 reset) and readable.

R/**W**/**E**_**P**: Multiple writable with value reset after power failure, H/W reset assertion and any CMD0 reset and readable.

W/E_P: Multiple writable with value reset after power failure, H/W reset assertion and any CMD0 reset and not readable.

Name	Field	Cell	Value	CSD-slice
		туре		(Byte)
Supported Command Sets	S_CMD_SET	R	1h	[504]
HPI features	HPI_FEATURES	R	3h	[503]
Background operations support	BKOPS_SUPPORT	R	1h	[502]
Max packed read commands	MAX_PACKED_READS	R	8h	[501]
Max packed write commands	MAX_PACKED_WRITES	R	8h	[500]
Data tag support	DATA_TAG_SUPPORT	R	1h	[499]
Tag unit size	TAG_UNIT_SIZE	R	0h	[498]
Tag Resource size	TAG_RES_SIZE	R	6h	[497]
Context management capabilities	CONTEXT_CAPABILITIES	R	78h	[496]
Large Unit Size	LARGE_UNIT_SIZE_M1	R	1h	[495]

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Extended partitions attribute support	EXT_SUPPORT	R	3h	[494]
Cache size	CACHE_SIZE	R	20000h	[252:249]
Generic CMD6 timeout	GENERIC_CMD6_TIME	R	64h	[248]
Power off notification(long) timeout	POWER_OFF_LONG_TIME	R	64h	[247]
Background operations status	BKOPS_STATUS	R	0h	[246]
Number of correctly programmed sectors	CORRECTLY_PRG_SECTOR S_NUM	R	0h	[245:242]
1 st initialization time after partitioning	INI_TIMEOUT_AP	R	Ah	[241]
Power class for 52MHz, DDR at 3.6V	PWR_CL_DDR_52_360	R	0h	[239]
Power class for 52MHz, DDR at 1.95V	PWR_CL_DDR_52_195	R	0h	[238]
Power class for 200MHz, at 1.95V	PWR_CL_200_195	R	0h	[237]
Power class for 200MHz, at 1.3V	PWR_CL_200_130	R	0h	[236]
Minimum Write Performance for 8bit at 52MHz in DDR mode	MIN_PERF_DDR_W_8_52	R	0h	[235]
Minimum Read Performance for 8bit at 52MHz in DDR mode	MIN_PERF_DDR_R_8_52	R	0h	[234]
TRIM Multiplier	TRIM_MULT	R	1h	[232]
Secure Feature support	SEC_FEATURE_SUPPORT	R	55h	[231]
Secure Erase Multiplier	SEC_ERASE_MULT	R	Ah	[230]
Secure TRIM Multiplier	SEC_TRIM_MULT	R	Ah	[229]
Boot information	BOOT_INFO	R	7h	[228]
Boot partition size	BOOT_SIZE_MULTI	R	20h	[226]



Access size	ACC_SIZE	R	6h	[225]
High-capacity erase unit size	HC_ERASE_GRP_SIZE	R	1h	[224]
High-capacity erase timeout	ERASE_TMEOUT_MULT	R	2h	[223]
Reliable write sector count	REL_WR_SEC_C	R	1h	[222]
High-capacity write protect group size	HC_WP_GRP_SIZE	R	10h	[221]
Sleep current (VCC)	S_C_VCC	R	7h	[220]
Sleep current (VCCQ)	S_C_VCCQ	R	7h	[219]
Sleep/awake timeout	S_A_TIMEOUT	R	13h	[217]
Sector Count	SEC_COUNT	R	Depends on capacity	[215:212]
Minimum Write Performance for 8bit at 52MHz	MIN_PERF_W_8_52	R	8h	[210]
Minimum Read Performance for 8bit at 52MHz	MIN_PERF_R_8_52	R	8h	[209]
Minimum Write Performance for 8bit at 26MHz, for 4bit at 52MHz	MIN_PERF_W_8_26_4_52	R	8h	[208]
Minimum Read Performance for 8bit at 26MHz, for 4bit at 52MHz	MIN_PERF_R_8_26_4_62	R	8h	[207]
Minimum Write Performance for 4 bit at 26MHz	MIN_PERF_W_4_26	R	8h	[206]
Minimum Read Performance for 4bit at 26MHz	MIN_PERF_R_4_26	R	8h	[205]
Power class for 26MHz at 3.6V 1 R	PWR_CL_26_360	R	0h	[203]



Power class for 52MHz at 3.6V 1 R	PWR_CL_52_360	R	0h	[202]
Power class for 26MHz at 1.95V 1 R	PWR_CL_26_195	R	0h	[201]
Power class for 52MHz at 1.95V 1 R	PWR_CL_52_195	R	0h	[200]
Partition switching timing	PARTITION_SWITCH_TIME	R	3h	[199]
Out-of-interrupt busy timing	OUT_OF_INTERRUPT_TIME	R	2h	[198]
I/O driver strength	DRIVER_STRENGTH	R	1h	[197]
Device type	DEVICE_TYPE	R	17h	[196]
CSD structure version	CSD_STRUCTURE	R	2h	[194]
Extended CSD revision	EXT_CSD_REV	R	6h	[192]
Command set	CMD_SET	R/W/E_P	0h	[191]
Command set revision	CMD_SET_REV	R	0h	[189]
Power class	POWER_CLASS	R/W/E_P	0h	[187]
High-speed interface timing	HS_TIMING	R/W/E_P	2h	[185]
High-speed interface timing Bus width mode	HS_TIMING BUS_WIDTH	R/W/E_P W/E_P	2h 2h	[185] [183]
High-speed interface timing Bus width mode Erased memory content	HS_TIMING BUS_WIDTH ERASED_MEM_CONT	R/W/E_P W/E_P R	2h 2h 0h	[185] [183] [181]
High-speed interface timing Bus width mode Erased memory content Partition configuration	HS_TIMING BUS_WIDTH ERASED_MEM_CONT PARTITION_CONFIG	R/W/E_P W/E_P R R/W/E & R/W/E_P	2h 2h 0h 0h	[185] [183] [181] [179]
High-speed interface timing Bus width mode Erased memory content Partition configuration Boot config protection	HS_TIMING BUS_WIDTH ERASED_MEM_CONT PARTITION_CONFIG BOOT_CONFIG_PROT	R/W/E_P W/E_P R R/W/E & R/W/E_P R/W & R/W/C_P	2h 2h 0h 0h 0h	[185] [183] [181] [179] [178]
High-speed interface timingBus width modeErased memory contentPartition configurationBoot config protectionBoot bus condition	HS_TIMING BUS_WIDTH ERASED_MEM_CONT PARTITION_CONFIG BOOT_CONFIG_PROT BOOT_BUS_CONDITION	R/W/E_P W/E_P R R/W/E & R/W/E_P R/W & R/W/C_P R/W/E	2h 2h 0h 0h 0h 0h	[185] [183] [181] [179] [178] [177]
High-speed interface timingBus width modeErased memory contentPartition configurationBoot config protectionBoot bus conditionHigh-density erase group definition	HS_TIMING BUS_WIDTH ERASED_MEM_CONT PARTITION_CONFIG BOOT_CONFIG_PROT BOOT_BUS_CONDITION ERASE_GROUP_DEF	R/W/E_P R R/W/E & R/W/E & R/W/E_P R/W & R/W/C_P R/W/E R/W/E	2h 2h 0h 0h 0h 0h 0h	[185] [183] [181] [179] [178] [177] [175]
High-speed interface timingBus width modeErased memory contentPartition configurationBoot config protectionBoot bus conditionHigh-density erase group definitionBoot area write protection	HS_TIMING BUS_WIDTH ERASED_MEM_CONT PARTITION_CONFIG BOOT_CONFIG_PROT BOOT_BUS_CONDITION ERASE_GROUP_DEF BOOT_WP	R/W/E_P W/E_P R R/W/E & R/W/E_P R/W & R/W/C_P R/W/E R/W/E	2h 2h 0h 0h 0h 0h 0h 0h	[185] [183] [181] [179] [178] [177] [175] [173]



		& R/W/E_P		
FW configuration	FW_CONFIG	R/W	0h	[169]
RPMB Size	RPMB_SIZE_MULT	R	20h	[168]
Write reliability setting register	WR_REL_SET	R/W	1Fh	[167]
Write reliability parameter register	WR_REL_PARAM	R	5h	[166]
Start Sanitize operation	SANITIZE_START	W/E_P	0h	[165]
Manually start background operations	BKOPS_START	W/E_P	0h	[164]
Enable background operations handshake	BKOPS_EN	R/W	0h	[163]
H/W reset function	RST_n_FUNCTION	R/W	0h	[162]
HPI management	HPI_MGMT	R/W/E_P	0h	[161]
Partitioning Support	PARTITIONING_SUPPORT	R	7h	[160]
Max Enhanced Area Size	MAX_ENH_SIZE_MULT	R	Depends on capacity	[159:157]
Partitions attribute	PARTITIONS_ATTRIBUTE	R/W	0h	[156]
Partitioning Setting	PARTITION_SETTING_COMP	R/W	0h	[155]
General Purpose Partition Size	GP_SIZE_MULT	R/W	0h	[154:143]
Enhanced User Data Area Size	ENH_SIZE_MULT	R/W	0h	[142:140]
Enhanced User Data Start Address	ENH_START_ADDR	R/W	0h	[139:136]
Bad Block Management mode	SEC_BAD_BLK_MGMNT	R/W	0h	[134]
Package Case Temperature is controlled	TCASE_SUPPORT	W/E_P	0h	[132]
Periodic Wake-up	PERIODIC_WAKEUP	R/W/E	0h	[131]

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Program CID/CSD in DDR mode support	PROGRAM_CID_CSD_DDR_ SUPPORT	R	0h	[130]
Vendor Specific Fields	VENDOR_SPECIFIC_FIELD	vendor specific	Reserved	[127:64]
UDA Quick Health info	UDA_HEALTH_STATUS	R	0h	[71:68]
EUDA Quick Health info	EUDA_HEALTH_STATUS	R	0h	[67:64]
Native sector size	NATIVE_SECTOR_SIZE	R	1h	[63]
Sector size emulation	USE_NATIVE_SECTOR	R/W	0h	[62]
Sector size	DATA_SECTOR_SIZE	R	0h	[61]
1st initialization after disabling sector size emulation	INI_TIMEOUT_EMU	R	Ah	[60]
Class 6 commands control	CLASS_6_CTRL	R/W/E_P	0h	[59]
Number of addressed group to be Released	DYNCAP_NEEDED	R	0h	[58]
Exception events control	EXCEPTION_EVENTS_CTRL	R/W/E_P	0h	[57:56]
Exception events status	EXCEPTION_EVENTS_STAT US	R	0h	[55:54]
Extended Partitions Attribute	EXT_PARTITIONS_ATTRIBU TE	R/W	0h	[53:52]
Context configuration	CONTEXT_CONF	R/W/E_P	0h	[51:37]
Packed command status	PACKED_COMMAND_STATU S	R	0h	[36]
Packed command failure index	PACKED_FAILURE_INDEX	R	0h	[35]
Power Off Notification	POWER_OFF_NOTIFICATIO	R/W/E_P	0h	[34]
Control to turn the Cache ON/OFF	CACHE_CTRL	R/W/E_P	0h	[33]
Flushing of the cache	FLUSH_CACHE	W/E_P	0h	[32]



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Revision History				
Version	Date	Modification Content		
V0.1	2015/03/23			
V0.2	2015/03/31			
V1.0	2015/04/08	Formal Release		